

RJK1211DPA

Silicon N Channel Power MOS FET Power Switching

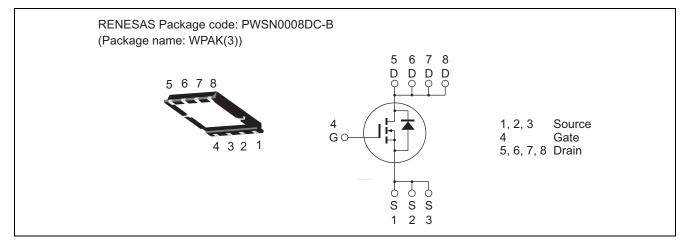
R07DS0089EJ0300 Rev.3.00 Apr 11, 2011

Datasheet

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
- $R_{DS(on)} = 100 \text{ m}\Omega \text{ typ.} (at V_{GS} = 10 \text{ V})$
- Pb-free
- Halogen-free

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	120	V
Gate to source voltage	V _{GSS}	+12, -5	V
Drain current	ID	5	А
Drain peak current	Note1 D(pulse)	15	А
Body-drain diode reverse drain current	I _{DR}	5	А
Avalanche current	I _{AP} Note 2	3	А
Avalanche energy	EAR Note 2	0.77	mJ
Channel dissipation	Pch Note3	15	W
Channel to case thermal impedance	θch-c ^{Note3}	8.33	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

- Notes: 1. PW \leq 10 μ s, duty cycle \leq 1% 2. Value at Tch = 25°C, Rg \geq 50 Ω

 - 3. Tc = 25°C



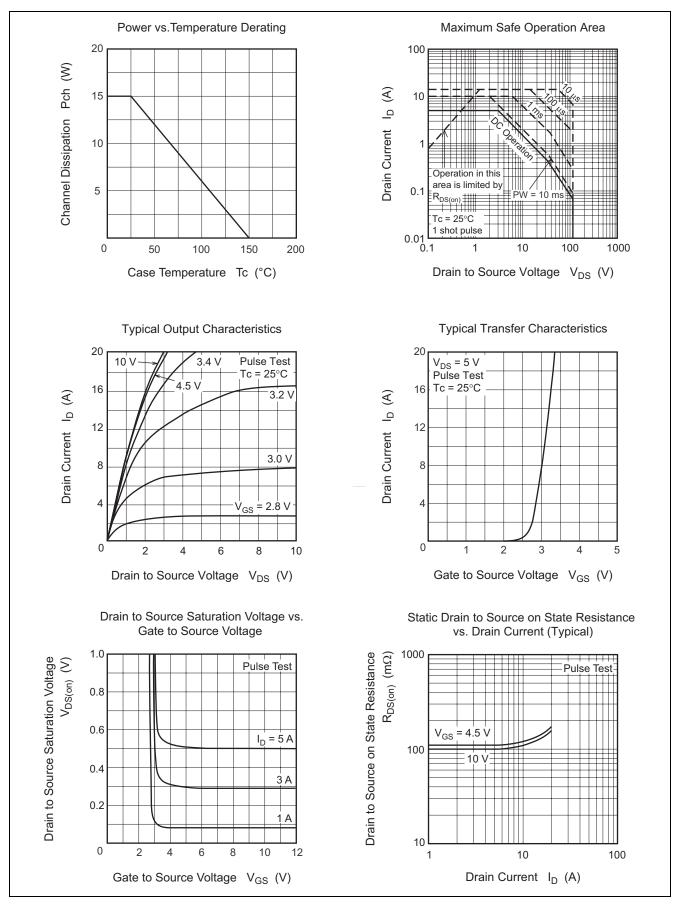
Electrical Characteristics

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	120	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	± 0.1	μΑ	V_{GS} = +12, -5 V, V_{DS} = 0
Zero gate voltage drain current	I _{DSS}	—	—	10	μΑ	$V_{DS} = 120 V, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.2	—	2.5	V	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	—	100	130	mΩ	$I_D = 2.5 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
resistance	R _{DS(on)}	—	110	150	mΩ	$I_D = 2.5 \text{ A}, V_{GS} = 4.5 \text{ V}^{Note4}$
Forward transfer admittance	y _{fs}	—	9.0	—	S	$I_D = 2.5 \text{ A}, V_{DS} = 5 \text{ V}^{Note4}$
Input capacitance	Ciss	_	1070	—	pF	V _{DS} = 10 V
Output capacitance	Coss	_	80	—	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	35	—	pF	
Gate Resistance	Rg	—	1.7	—	Ω	
Total gate charge	Qg	—	8.0	—	nC	$V_{DD} = 50 V$ $V_{GS} = 4.5 V$ $I_D = 5 A$
Gate to source charge	Qgs	_	3.0	—	nC	
Gate to drain charge	Qgd	—	2.0	—	nC	
Turn-on delay time	t _{d(on)}	—	7.8	—	ns	$V_{GS} = 10 \text{ V}, I_D = 2.5 \text{ A}$
Rise time	tr		2.8	—	ns	$V_{DD} \cong 30 \text{ V}$ $R_{L} = 12 \Omega$ $Rg = 4.7 \Omega$
Turn-off delay time	t _{d(off)}		38	—	ns	
Fall time	t _f		2.7	—	ns	
Body-drain diode forward voltage	V _{DF}	_	0.83	1.1	V	$I_F = 5 \text{ A}, V_{GS} = 0^{Note4}$
Body-drain diode reverse recovery	t _{rr}		40	—	ns	$I_F = 5 A, V_{GS} = 0$
time						di _F / dt = 100 A/ μs

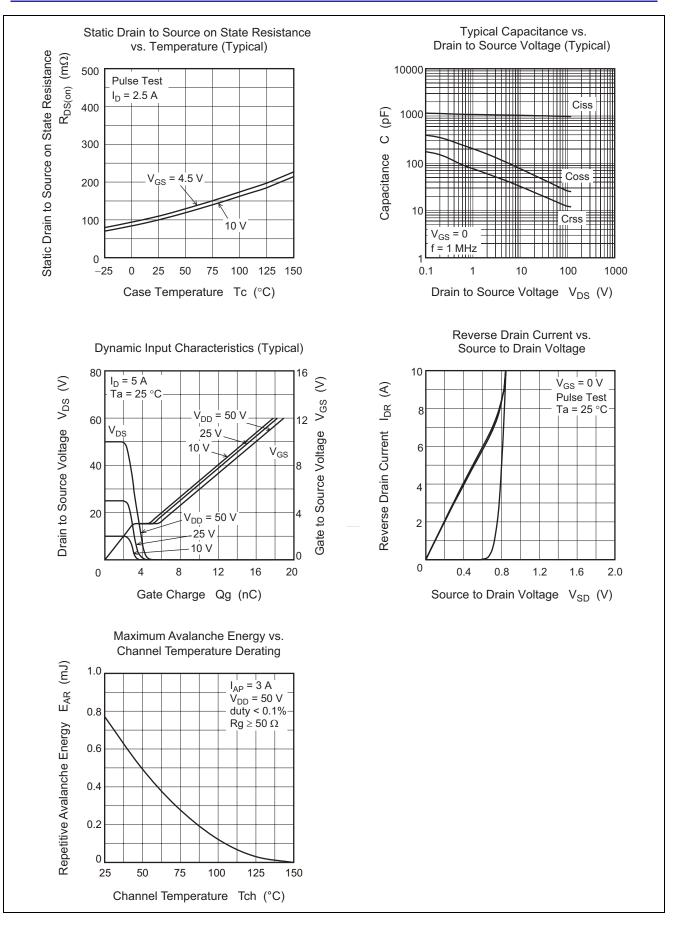
Notes: 4. Pulse test



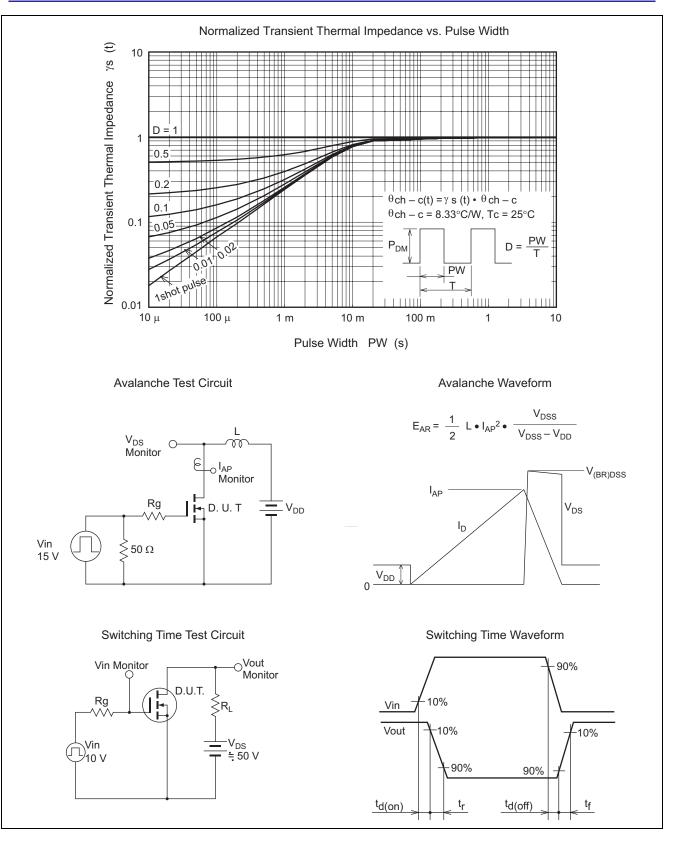
Main Characteristics



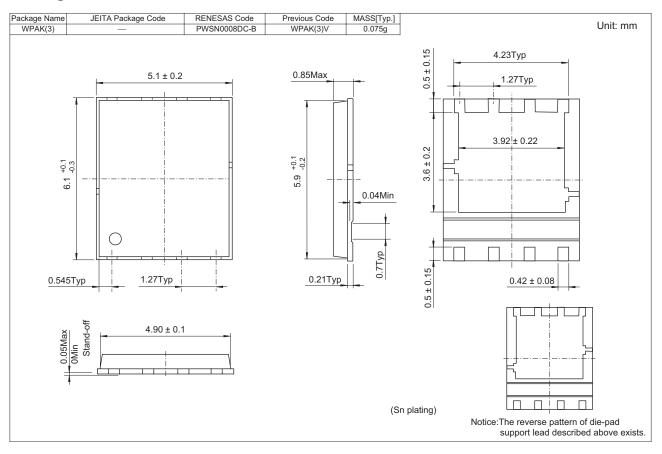








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK1211DPA-00-J5A	3000 pcs	Taping



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